

# 2N4400



## **MMBT4400**



## NPN General Purpose Amplifier

This device is designed for use as general purpose amplifiers and switches requiring collector currents to 500 mA.

### **Absolute Maximum Ratings\*** TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CEO</sub>	Collector-Emitter Voltage	40	V
V <sub>CBO</sub>	Collector-Base Voltage	60	V
V <sub>EBO</sub>	Emitter-Base Voltage	6.0	V
I <sub>C</sub>	Collector Current - Continuous	600	mA
T <sub>J</sub> , T <sub>stg</sub>	Operating and Storage Junction Temperature Range	-55 to +150	°C

\*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

### NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

### Thermal Characteristics

TA = 25°C unless otherwise noted

Symbol	Characteristic	M	lax	Units
		2N4400	*MMBT4400	
P <sub>D</sub>	Total Device Dissipation Derate above 25°C	625 5.0	350 2.8	mW mW/∘C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3		°C/W
$R_{ ext{ hetaJA}}$	Thermal Resistance, Junction to Ambient	200	357	°C/W

# NPN General Purpose Amplifier (continued)

Electri	Electrical Characteristics TA = 25°C unless otherwise noted				
Symbol	Parameter	Test Conditions	Min	Мах	Units

### **OFF CHARACTERISTICS**

V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage*	$I_{\rm C} = 1.0 \text{ mA}, I_{\rm B} = 0$	40		V
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	$I_{C} = 100 \ \mu A, \ I_{E} = 0$	60		V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	$I_{\rm E} = 100 \ \mu {\rm A}, \ I_{\rm C} = 0$	6.0		V
I <sub>CEX</sub>	Collector Cutoff Current	$V_{CE} = 35 \text{ V}, V_{EB} = 0.4 \text{ V}$		0.1	μΑ
I <sub>BL</sub>	Emitter Cutoff Current	$V_{CE} = 35 \text{ V}, V_{EB} = 0.4 \text{ V}$		0.1	μΑ

### **ON CHARACTERISTICS\***

h <sub>FE</sub>	DC Current Gain	$V_{CE} = 1.0 \text{ V}, I_{C} = 1.0 \text{ mA}$	20		
		$V_{CE} = 1.0 \text{ V}, I_{C} = 10 \text{ mA}$	40		
		$V_{CE} = 1.0 \text{ V}, I_{C} = 150 \text{ mA}$	50	150	
		$V_{CE} = 2.0 \text{ V}, I_{C} = 500 \text{ mA}$	20		
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 150 mA, I <sub>B</sub> =15 mA		0.40	V
()		$I_{\rm C} = 500 \text{ mA}, I_{\rm B} = 50 \text{ mA}$		0.75	V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = 150 mA, I <sub>B</sub> =15 mA	0.75	0.95	V
()		$I_{\rm C} = 500 \text{ mA}, I_{\rm B} = 50 \text{ mA}$		1.2	V

### SMALL SIGNAL CHARACTERISTICS

C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = 5.0 V, f = 140 kHz		6.5	pF
C <sub>ib</sub>	Input Capacitance	V <sub>EB</sub> = 0.5 V, f = 140 kHz		30	pF
h <sub>fe</sub>	Small-Signal Current Gain	$I_{C} = 20 \text{ mA}, V_{CE} = 10 \text{ V},$ f = 100 MHz	2.0		
h <sub>fe</sub>	Small-Signal Current Gain	$V_{CE} = 10 \text{ V}, I_{C} = 1.0 \text{ mA},$	20	250	
h <sub>ie</sub>	Input Impedance	f = 1.0 kHz	0.5	7.5	KΩ
h <sub>re</sub>	Voltage Feedback Ratio		0.1	8.0	x 10 <sup>-4</sup>
h <sub>oe</sub>	Output Admittance		1.0	30	μmhos

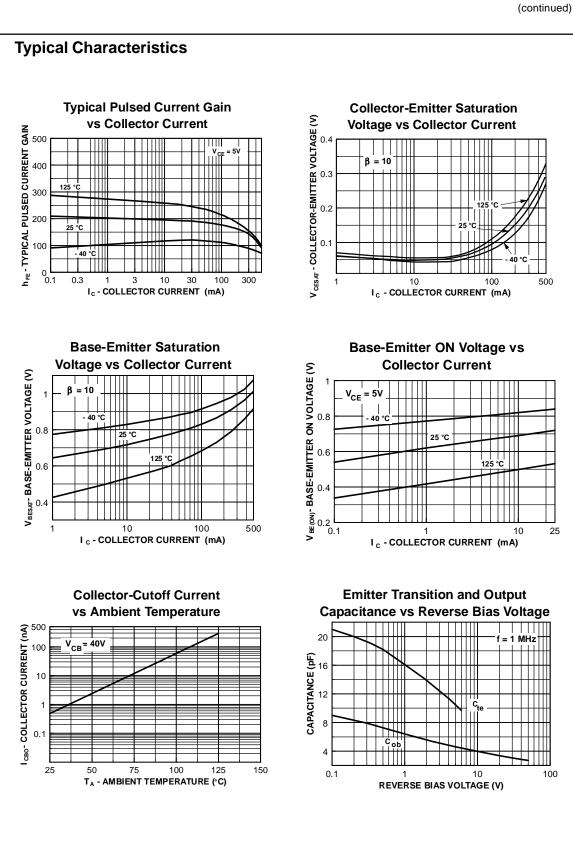
### SWITCHING CHARACTERISTICS

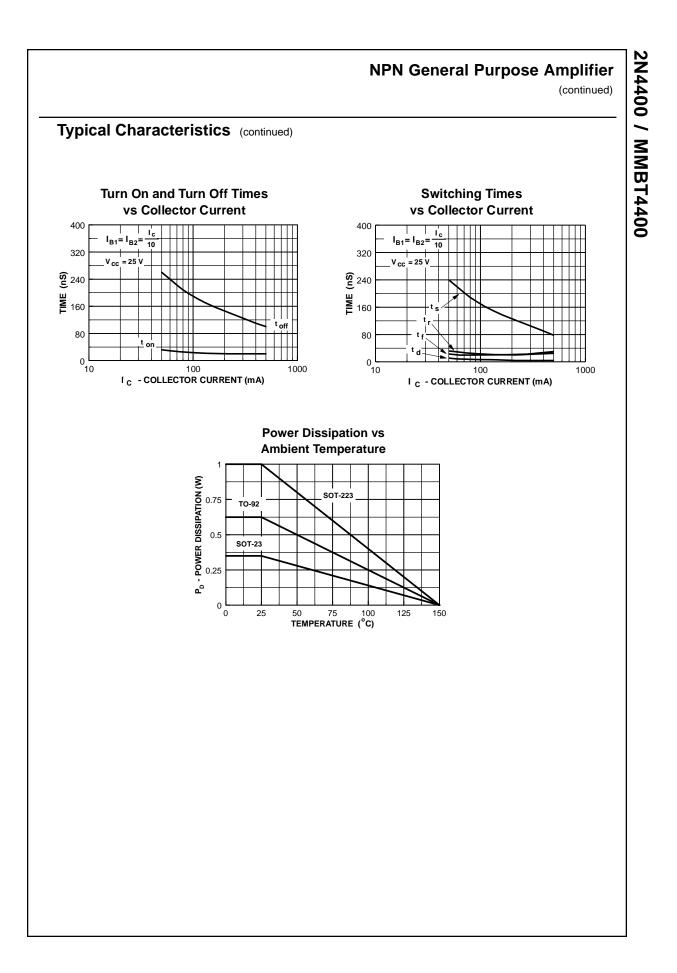
t <sub>d</sub>	Delay Time	$V_{\rm CC} = 30 \text{ V}, \text{ I}_{\rm C} = 150 \text{ mA},$	15	ns
tr	Rise Time	I <sub>B1</sub> = 15 mA ,V <sub>EB</sub> = 2 V	20	ns
ts	Storage Time	$V_{CC} = 30 \text{ V}, I_{C} = 150 \text{ mA}$	225	ns
t <sub>f</sub>	Fall Time	$I_{B1} = I_{B2} = 15 \text{ mA}$	30	ns

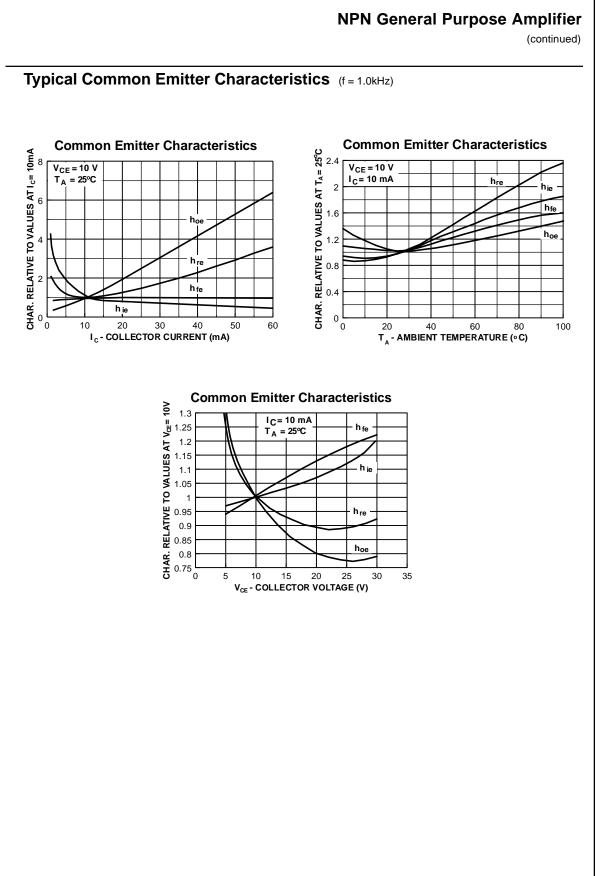
\*Pulse Test: Pulse Width £ 300 ms, Duty Cycle £ 2.0%

# 2N4400 / MMBT4400

**NPN General Purpose Amplifier** 



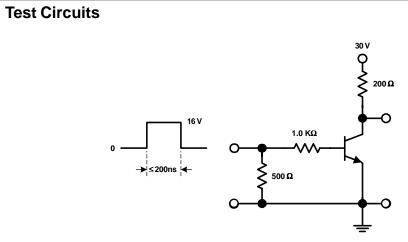




2N4400 / MMBT4400

# NPN General Purpose Amplifier

(continued)



### FIGURE 1: Saturated Turn-On Switching Timer

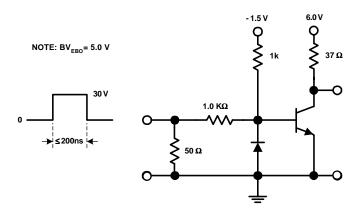


FIGURE 2: Saturated Turn-Off Switching Time

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